# Effects of disorder on high-temperature superconductivity in cubic MoN

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Three types of calculations have been used to help us understand the effects of disorder, alloying, and nonstoichiometry on the superconducting transition temperature  $T_c$  of MoN, predicted to have  $T_c = 29$  K in the ideal B 1 structure. (1) Simple disorder broadening indicates a strong lowering of  $T_c$  which, however, does not account for the very low  $T_c$ 's measured in MoN<sub>x</sub> thin films. (2) Rigid-band calculations of the alloy system Nb<sub>1-y</sub>Mo<sub>y</sub>N<sub>1.0</sub> reproduce the measured trend in  $T_c$  for  $y \leq 0.5$ . (3) Taking explicit account of metal  $t_{2g}$ -N p bonding in a coherent-potential-approximation model of MoN<sub>x</sub> leads to a semiquantitative understanding of the low measured  $T_c$  values in films in terms of N vacancies, despite the nominal stoichiometry in some of the films.

## I. INTRODUCTION

In recent publications<sup>1-3</sup> it has been proposed that on the basis of energy-band-structure calculations the compound MoN, in the NaCl structure, is predicted to have a superconducting transition temperature  $T_c \sim 29$  K. These calculations correspond strictly only to the ordered stoichiometric case. It could be argued that the above prediction is not realistic for a high- $T_c$  transition-metal nitride because this class of compounds tends to form with vacancies on the nitrogen sublattice. Moreover, Linker et al.<sup>4</sup> have fabricated nominally stoichiometric but not highly ordered MoN in the NaCl structure, which displays a value of  $T_c$  which is an order of magnitude below the predicted value. Although recent experimental studies of the Mo-Nb-N-C system by Wolf et al.<sup>5</sup> have shown a trend of increasing  $T_c$  with increasing Mo content, they have not produced the predicted high  $T_c$  for the MoN end.

To check the effects of disorder, alloying, and nonstoichiometry in this system we have (a) calculated the effects of disorder on the density of states (DOS) of the stoichiometric MoN using the electron-lifetime model (ELM),<sup>6-8</sup> (b) applied the rigid-band model on the band structures of NbN and MoN to estimate the electronphonon interaction and  $T_c$  for the alloy system Nb<sub>1-y</sub>Mo<sub>y</sub>N<sub>1.0</sub>, and (c) used the tight-binding coherentpotential-approximation (CPA) method<sup>9</sup> to examine the effect of nitrogen vacancies.

#### **II. ELECTRON-LIFETIME MODEL**

The ELM assumes that defects simply broaden the DOS via the electron relaxation time,  $\tau$ , which decreases with disorder. One then takes into account disorder effects by the following convolution of the DOS,  $N(E', \Gamma=0)$ :

$$N(E,\Gamma) = \int S(E,E',\Gamma)N(E',\Gamma=0)dE', \qquad (1)$$

where  $S(E,E',\Gamma)$  is a broadening function which depends on the electron damping  $\Gamma = \hbar/\tau$ . In the present calculation  $S(E,E',\Gamma)$  is a Lorentzian whose half-width  $\Gamma$  is related to the infrared plasma energy  $\Omega_p$  and the residual resistivity  $\rho_0$  arising from disorder by the formula

$$\Gamma = 1.341 \times 10^4 \Omega_p^2 \rho_0 , \qquad (2)$$

where  $\Omega_p$  is expressed in eV and  $\rho_0$  in  $\mu\Omega$  cm. The physical interpretation of this relation is discussed in Ref. 7.

A relation analogous to Eq. (1) was applied to broaden our calculated  $\Omega_p^2$  to obtain  $\Omega_p^2(\Gamma)$ , which was substituted into Eq. (2) to obtain the corresponding values of  $\rho_0$ . In order to relate  $N(E_F)$  and  $\Omega_p(E_F)$  to the experimental  $\rho_{\text{expt}}$  we have made use of the fact that high- $T_c$  metals display a temperature-dependent resistivity which is well described<sup>10</sup> by the parallel resistor formula

$$\frac{1}{\rho_{\text{expt}}} = \frac{1}{\rho_0} + \frac{1}{\overline{\rho}} \ . \tag{3}$$

We use the canonical value<sup>10</sup> of  $\bar{\rho} = 150 \,\mu\Omega$  cm.

The results for  $N(E_F,\Gamma)$  are displayed in Fig. 1. We note that for an amount of disorder corresponding to  $\rho_{expt}=32 \ \mu\Omega \ cm \ (\rho_0=40 \ \mu\Omega \ cm) \ N(E_F,\Gamma)$  drops from a value of 15.5 states/Ry spin (see Table I and Ref. 3) at



FIG. 1. Ratio of the Fermi-level density of states in disordered MoN to that of ideal B1 MoN, inferred from the electron-lifetime model vs the experimental residual resistivity  $\rho_{0}$ .

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y	$N(E_F)$	$\eta_M$	$\eta_{ m N}$	$\lambda_M$	$\lambda_N$	$\lambda_{tot}$	$\mu^*$	$\omega_{ m log}$	T <sub>c</sub>
				Rigid band	from NbN	-			
0.0	6.43	6.98	3.18	0.77	0.19	0.96	0.098	258	17.1
0.1	6.70	6.81	2.80	0.74	0.17	0.91	0.099	254	15.1
0.2	6.71	6.67	2.66	0.71	0.16	0.87	0.099	256	14.1
0.3	6.13	5.86	2.51	0.61	0.15	0.76	0.095	263	11.6
0.4	6.17	5.67	2.52	0.58	0.15	0.73	0.095	269	10.8
0.5	6.45	5.68	2.65	0.57	0.16	0.73	0.097	275	10.8
				Rigid band	from MoN				
0.5	7.67	7.00	2.70	0.71	0.16	0.87	0.106	263	13.9
0.6	8.66	7.81	3.13	0.77	0.19	0.96	0.112	268	16.5
0.7	10.00	9.15	3.67	0.89	0.22	1.11	0.119	271	20.3
0.8	12.36	10.30	3.49	0.99	0.21	1.20	0.129	264	20.9
0.9	14.45	12.99	4.57	1.22	0.27	1.49	0.136	269	27.4
1.0	15.50	13.84	5.05	1.28	0.30	1.58	0.139	276	29.4

TABLE I. Quantities related to the superconducting transition temperature  $T_c$  for the Nb<sub>1-y</sub>Mo<sub>y</sub>N<sub>1.0</sub> system, based on a rigidband model from each end. The units are  $N(E_F)$  (Ry spin-cell)<sup>-1</sup>,  $\eta(eV/Å^2)$ ,  $\lambda$  and  $\mu^*$  (dimensionless),  $\omega_{\log}$ , and  $T_c$  (K).

 $\rho_{\text{expt}}=0$ , to a value of 10.3 states/Ry spin. Although this is a significant lowering of  $N(E_F,\Gamma)$  we note that this is still a rather high DOS at  $E_F$ . For comparison we mention here that NbN, a superconductor with  $T_C \approx 17$  K, has  $N(E_F,0)=6.43$  states/Ry spin (see Ref. 3). Therefore, we conclude that this unspecified form of disorder which serves only to broaden N(E) will lower  $T_c$  from our suggested value for stoichiometric MoN. However, up to rather high levels of disorder it still gives a  $T_c$ higher than that of NbN.

#### III. RIGID-BAND MODEL FOR Nb1-yMoyN1.0

In an earlier publication<sup>11</sup> one of us applied the rigidband approximation (RBA) on the band structures of NbC and NbN to evaluate the electron-ion interaction constant  $\eta$  and  $T_c$  for the system of Nb-C-N. These calculations reproduced very well the overall variation of  $T_c$ shown in the experiments. In a similar manner we used here the band-structure results for NbN and MoN to obtain partial DOS,  $N_l$ , and scattering phase shifts,  $\delta_l$ , for the alloy Nb<sub>1-y</sub>Mo<sub>y</sub>N<sub>1.0</sub> needed in the determination of  $\eta$ by the theory of Gaspari and Gyorffy.<sup>12</sup> In our scheme, in the range 0 < y < 0.5, we used the  $N_l$ 's and  $\delta_l$ 's from the NbN band structure while in the range  $0.5 \le y < 1.0$ we used the corresponding quantities from the MoN band structure.

Our results show that  $\eta_{Mo}$  (Nb) is roughly a factor of ~2.5 larger than  $\eta_N$  through the whole range of y. The value of  $\eta_N$  is 3.2 eV/Å<sup>2</sup> at the NbN end (y =0), decreases to 2.5 eV/Å<sup>2</sup> at y = 0.3-0.4, and then increases monotonically to 5.1 eV/Å<sup>2</sup> at y = 1.0. The value of  $\eta_{Mo}$  (Nb) is 7.0 eV/Å<sup>2</sup> for y = 0, decreases to 5.7 eV/Å<sup>2</sup> at y = 0.45, and then increases to 13.8 eV/Å<sup>2</sup> at the MoN end (y = 1.0). To calculate the electron-phonon coupling constant  $\lambda$  we have used neutron-scattering data and Debye-temperature measurements of the NbC<sub>1-x</sub>N<sub>x</sub> sys-

tem as discussed in Ref. 3. We then employ the Allen-Dynes<sup>13</sup> equation to calculate  $T_c$  with a DOS dependent  $\mu^*$  given by a modified<sup>11</sup> Bennemann-Garland<sup>14</sup> formula. Our results for the intermediate quantities and  $T_c$  are displayed in Table I. A plot of  $T_c$  as a function of Mo content is shown in Fig. 2. We note that  $T_c$  follows the variation of  $\eta$  or  $\lambda$ , i.e., it decreases from 17 K at the NbN end, reaches a minimum of 11 K at about y = 0.4, and increases to 29 K at the MoN end. Recent measurements by Wolf *et al.*<sup>5</sup> show a decrease of  $T_c$  with increasing y in agreement with that portion of the graph shown in Fig. 2. The calculated increase of  $T_c$  for the Mo-rich end has not been observed due to experimental difficulties in retaining a stoichiometric and ordered B1 structure for high-Mo concentrations.



FIG. 2. Superconducting transition temperature  $T_c$  of Nb<sub>1-y</sub>Mo<sub>y</sub>N alloys, based on a rigid-band model on the end points NbN and MoN.

#### IV. CPA CALCULATIONS FOR MoN<sub>x</sub>

In Sec. II an unspecified disorder broadening was applied to the density of states of MoN. In this section we present results of a calculation performed utilizing the CPA to study the effects on the electronic structure of vacancies on the nitrogen sublattice in MoN. Our model assumes that the metal sublattice remains unchanged while the nitrogen sublattice contains vacancies at random. The tight-binding CPA theory that we used here originates from the work of Faulkner<sup>9</sup> on PdH which was previously extended<sup>15</sup> to include both s and p orbitals in the basis set of the vacancy atom. This involves a Slater-Koster tightbinding fit to the MoN energy bands and subsequent solution of the CPA condition for zero-average scattering from which the nonmetal sublattice self-energies  $\sum_{s}$  and  $\sum_{p}$  are determined. The quantities  $\sum_{s}$  and  $\sum_{p}$  are then used to calculate an effective Green's function from which the DOS are found.

We performed these calculations for nitrogen concentrations  $1.0 < x \le 0.5$  in steps of 0.1. In Fig. 3 we show



FIG. 3. Total density of states of  $MoN_x$  for the three nitrogen concentrations x = 0.8, 0.9, and 1.0, based on the tightbinding CPA model.

the DOS for x = 0.9 and 0.8 together with the stoichiometric case x = 1.0. We note from Fig. 3 that the main characteristics of the stoichiometric MoN DOS are preserved upon the creation of vacancies. That is, we have a low-lying peak at about -0.3 Ry, due to the nitrogen s states, then a broader peak at about 0.4 Ry which corresponds to a mixture of Mo d states and N p states, and near the Fermi level another broad peak containing predominantly Mo states. The value of  $N(E_F)$  remains within 1-2% of the stoichiometric value and the value of  $E_F$  changes by no more than  $\pm 1$  mRy as a function of x. This is different from the situation reported in Ref. 15 for NbC where  $E_F$  increases with decreasing x by approximately 20 mRy per  $\Delta x = 0.1$ . We believe that this different behavior of  $E_F$  with x between MoN and the carbides is due to the fact that around  $E_F$  the p-C electrons experience a much stronger hybridization with the d electrons in the carbides than do the p-N electrons in the nitrides. The much larger value of  $N(E_F)$  in MoN also serves to "pin" the Fermi level to some degree.

To quantify the variation of  $\eta$  with the amount of vacancies we note first that according to the earlier analysis of the bonding characteristics of transition-metal carbides,<sup>15</sup> the metal-to-carbon charge transfer comes primarily from the metal  $t_{2g}$  states to the carbon p states. An examination of the integrated components of the DOS supports the same conclusion for MoN. Therefore, the concentration dependence of  $\eta$  will be dominated by that of the N p and Mo  $t_{2g}$  DOS.

One would like to have a quantitative theoretical description of the change in  $T_c$  due to vacancies on the nonmetal sublattice. Unfortunately, there is no viable microscopic theory for the electron-phonon interaction  $\lambda$  for such systems. The theory of Gaspari and Gyorffy (GG),<sup>12</sup> which makes the rigid muffin-tin approximation, has been applied widely and successfully in high-symmetry transition-metal-based compounds. However, this theory becomes much more approximate when applied to systems such as MoN<sub>x</sub>, partially due to Mo atoms adjacent to vacancies (six Mo atoms for each vacancy) acquiring a much lower symmetry than cubic, and perhaps differing greatly in their scattering properties from an averagelattice CPA "atom." In addition, the tight-binding CPA does not provide the changes in phase shifts which are needed in the GG theory. Ignoring changes in phase shifts and estimating from the calculated CPA local DOS, the GG theory applied directly to  $MoN_x$  would lead to only a small decrease in  $\lambda$  for  $x \approx 0.5$ . However, the strong decrease in  $T_c$  in both NbC and NbN and the disappearance of phonon anomalies<sup>16</sup> in NbC, as x decreases, both indicate a large reduction in electron-phonon coupling compounds due to vacancies.

We instead adopt the point of view that the metal $d_{t_{2g}}$ -nonmetal-p interaction is crucial to the strong electron-phonon coupling in stoichiometric MoN. This feature, which is not evident in the GG expression, was first discussed in detail for NbC by Schwarz and Rösch.<sup>17</sup> To be specific, we expect that the decrease in  $\eta$  will arise from contributions proportional to the  $t_{2g}$  and p DOS of the Mo and N atoms, respectively. The x dependence of  $\eta$  is taken in the GG-like form<sup>18,19</sup>

TABLE II. Density-of-states ratios and superconducting parameters in  $MoN_x$ , based on the tight-binding CPA model. Units are as in Table I.

x	$N_p^N/N$	$N_{t_{2g}}^{\mathrm{Mo}}/N$	$\eta_{ m N}$	$\eta_{ m Mo}$	$\lambda_N$	$\lambda_{Mo}$	$\lambda_{tot}$	$\omega_{\log}$	$\mu^*$	T <sub>c</sub>
1.0	0.079	0.752	5.1	13.8	0.30	1.28	1.58	275	0.139	29.4
0.9	0.067	0.733	4.3	13.4	0.23	1.03	1.26	299	0.139	24.4
0.8	0.061	0.714	3.9	13.1	0.19	0.84	1.03	326	0.139	19.7
0.7	0.053	0.691	3.4	12.7	0.15	0.70	0.85	351	0.139	14.3
0.6	0.045	0.662	2.9	12.2	0.12	0.58	0.70	374	0.139	9.0
0.5	0.036	0.629	2.3	11.5	0.09	0.47	0.56	393	0.139	4.3

$$\eta_{Mo}(x) = N(E_F, x) \langle I_{Mo}^{2}(E_F, x) \rangle$$

$$= N(E_F, x) \left[ C_{Mo} \frac{N_t^{Mo}(E_F, x)}{N(E_F, x)} \right],$$

$$\eta_{N}(x) = N(E_F, x) \langle I_{N}^{2}(E_F, x) \rangle$$

$$= N(E_F, x) \left[ C_{N} \frac{N_p^{N}(E_F, x)}{N(E_F, x)} \right],$$
(4)

where the constants  $C_i$  are proportional to the normalized atomic electron-ion matrix elements discussed by Pickett<sup>18</sup> and are determined from the values of  $\eta_{Mo}$  and  $\eta_N$  at x = 1.0. The understanding of the x dependence of  $\eta$  in MoN<sub>x</sub> is simplified further by noting that the CPA calculations indicate that the total DOS  $N(E_F,x)$  changes very little with x. The results of the calculation of  $\eta$  using Eqs. (4) are shown in Table II. We note that the value of  $\eta_N$  is reduced by 24% and that of  $\eta_{Mo}$  by 5% at x = 0.8, and further reductions occur for smaller x's.

Since the electron-phonon coupling constant  $\lambda$  is a ratio of the electronic part  $\eta$  and a phononic part  $M\langle\omega^2\rangle$ , we need to account for the variation of  $M\langle\omega^2\rangle$  with x. This we include in a phenomenological model of the x dependence of the phonon spectrum.<sup>16,20</sup> We assume an increase of  $\langle\omega^2\rangle$  which is proportional to the vacancy concentration 1-x. We postulate the formulas

$$\langle \omega_{\rm Mo}^2(x) \rangle = \langle \omega_{\rm Mo}^2(1) \rangle + (1-x) \langle \omega_{\rm Mo}^2(1) \rangle ,$$

$$\langle \omega_{\rm N}^2(x) \rangle = \langle \omega_{\rm N}^2(1) \rangle + \frac{1}{2} (1-x) \langle \omega_{\rm N}^2(1) \rangle .$$

$$(5)$$

In Eqs. (5) we made a smaller change, by a factor of 2, of  $\langle \omega^2 \rangle$  for the optic mode. This is consistent with the analysis of experimental data in Ref. 20, and leads to an

overall 39% reduction of  $\lambda$  at x = 0.8. The variation of  $\lambda$  with x and the resulting  $T_c$  are shown in Table II. The transition temperature  $T_c \sim 29$  K that we calculated for stoichiometric MoN is drastically decreased, for the non-stoichiometric alloy MoN, down to 4.3 K at x = 0.5.

# **V. CONCLUSIONS**

Three types of calculations have been applied to help understand the effects of alloying and disorder in MoN. Although a general broadening of the DOS strongly decreases  $T_c$ , it will not account alone for the low measured  $T_c$  in films. Taking into account vacancies on the nitrogen sublattice leads to a consistent semiguantitative picture of the experimental data. As an example our calculations indicate that 30% vacancies on the nitrogen sublattice could decrease  $T_c$  by about a factor of 2 from our prediction for the fully ordered stoichiometric MoN. This is still a sufficiently high transition temperature to justify further experimental studies of this prototype of a material with very strong electron-phonon coupling. We wish to emphasize that in our calculations we have not included any disorder on the Mo sublattice. We believe that vacancies on the Mo sublattice or substitutions of Mo by N will further reduce  $T_c$ . We speculate that degradation of the Mo sublattice may contribute to the low  $T_c$  observed in recent experiments.4,5

#### ACKNOWLEDGMENTS

We wish to thank L. L. Boyer, D. U. Gubser, B. M. Klein, and S. A. Wolf for useful discussions, and L. N. Blohm and K. Blathras for technical assistance. One of us (D.A.P.) wishes to acknowledge the hospitality of the Research Center of Crete where some parts of these calculations were performed.

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